

# PROCEEDINGS OF SPIE

## Physical Chemistry of Semiconductor Materials and Interfaces XIX

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24 August – 4 September 2020  
Online Only, United States

Sponsored and Published by  
SPIE

Volume 11464

Proceedings of SPIE 0277-786X, V. 11464

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Author(s), "Title of Paper," in *Physical Chemistry of Semiconductor Materials and Interfaces XIX*, edited by Christian Nielsen, Daniel Congreve, Andrew J. Musser, Proceedings of SPIE Vol. 11464 (SPIE, Bellingham, WA, 2020) Seven-digit Article CID Number.

ISSN: 0277-786X

ISSN: 1996-756X (electronic)

ISBN: 9781510637344

ISBN: 9781510637351 (electronic)

Published by

SPIE

P.O. Box 10, Bellingham, Washington 98227-0010 USA

Telephone +1 360 676 3290 (Pacific Time) · Fax +1 360 647 1445

[SPIE.org](http://SPIE.org)

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